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	Type L#	F #	Hits	Search Text	DBs	Time Stamp	Com ment s	Com r Erment Defi ros s nitio rs	ro rs
								u	
	IS&R L1		,	("6417084").PN.	USPAT; US-PGPUB 2003/11/30 18:10	2003/11/30 18:10			0
2	IS&R L2	1.2		("6506649").PN.	USPAT; US-PGPUB	2003/11/30 15:23			0
	BRS	L3		"4074300".PN.	USPAT	2003/11/30 15:24			0
₹†	BRS	[74	0	6506649.URPN.	USPAT	2003/11/30 15:25			0
\ \tag{\chi}	IS&R L5	L5	-	("5688704").PN.	USPAT; US-PGPUB	2003/11/30 18:23			0
5	BRS	9T	16	5688704.URPN.	USPAT	2003/11/30 18:11			0
7	IS&R L8	į	81	(438/182).CCLS.	USPAT; US-PGPUB	2003/11/30 18:26			0
80	IS&R L9		952	(438/303).CCLS.	USPAT; US-PGPUB $\begin{vmatrix} 2003/11/30 \\ 18:27 \end{vmatrix}$	2003/11/30 18:27			0

L Number	Hits	Search Text	DB	Time stamp
•	6	(("6417084") or ("6313019") or ("6319802") or ("6403456") or	USPAT;	2003/01/15 11:45
		("6270929") or ("6255202")).PN.	US-PGPUB	2002/01/15 12 55
-	6	(("6417084") or ("6313019") or ("6319802") or ("6403456") or ("6270929") or ("6255202")).PN.	USPAT; US-PGPUB	2003/01/15 13:55
_	584685	(aperture\$1 or opening\$1 or opening\$1 or trench\$2 or hole\$1 or	USPAT;	2003/01/15 14:28
		groov\$3) near4 (first or small\$2)	US-PGPUB;	
			ЕРО; ЛРО;	
			DERWENT;	
	537987	(aperture\$1 or opening\$1 or openning\$1 or trench\$2 or hole\$1 or	IBM_TDB USPAT;	2003/01/15 14:30
	231761	groov\$3) near4 (second or another or big\$4 or larg\$3)	US-PGPUB;	2003/01/13 14.30
			ЕРО; ЈРО;	
			DERWENT;	
	000000	04 11 1101 11 1101 (11 1101)	IBM_TDB	2002/01/15 14 21
-	900899	spacer\$1 or sidewall\$1 or side-wall\$1 or (side adj wall\$1)	USPAT; US-PGPUB;	2003/01/15 14:31
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	99359	(silicon near2 nitride) or (silicon adj rich adj nitride) or SiRN or "SiRN"	USPAT;	2003/01/15 14:31
		or oxynitride or oxy-nitride or (oxy adj nitride) or (silicon adj	US-PGPUB;	
		oxynitride)	EPO; JPO; DERWENT;	
			IBM TDB	
_	15872	T-gate\$1 or T-electrode\$1 or T-conductor\$1 or (T-shaped adj (gate\$1 or	USPĀT;	2003/01/15 14:34
		electrode\$1 or conductor\$1)) or ("T" near3 (gate\$1 or electrode\$1 or	US-PGPUB;	
		conduct\$8))	ЕРО; ЛРО;	
			DERWENT; IBM_TDB	
	321384	((aperture\$1 or opening\$1 or openning\$1 or trench\$2 or hole\$1 or	USPAT;	2003/01/15 14:35
	321304	groov\$3) near4 (first or small\$2)) and ((aperture\$1 or opening\$1 or	US-PGPUB;	2000101111011110
		openning\$1 or trench\$2 or hole\$1 or groov\$3) near4 (second or another	ЕРО; ЈРО;	
		or big\$4 or larg\$3))	DERWENT;	
	174	(((aperture\$1 or opening\$1 or openning\$1 or trench\$2 or hole\$1 or	IBM_TDB USPAT;	2003/01/15 14:35
· •	174	groov\$3) near4 (first or small\$2)) and ((aperture\$1 or opening\$1 or	US-PGPUB;	2003/01/13 14.33
		openning\$1 or trench\$2 or hole\$1 or groov\$3) near4 (second or another	ЕРО; ЈРО;	
		or big\$4 or larg\$3))) and (spacer\$1 or sidewall\$1 or side-wall\$1 or (side	DERWENT;	
		adj wall\$1)) and ((silicon near2 nitride) or (silicon adj rich adj nitride)	IBM_TDB	
		or SiRN or "SiRN" or oxynitride or oxy-nitride or (oxy adj nitride) or (silicon adj oxynitride)) and (T-gate\$1 or T-electrode\$1 or		
		T-conductor\$1 or (T-shaped adj (gate\$1 or electrode\$1 or conductor\$1))		
		or ("T" near3 (gate\$1 or electrode\$1 or conduct\$8)))		
-	6	(aperture\$1 or opening\$1 or openning\$1 or trench\$2 or hole\$1 or	USPAT;	2003/01/15 15:06
		groov\$3) with (RELACS or (resist\$3 adj enhanc\$7 adj (lithograph\$3 or	US-PGPUB;	
		litho-graph\$3 or (litho adj graph\$3)) adj assist\$3 adj2 chemical adj shrink\$3))	EPO; JPO; DERWENT;	:
		Sill filk \$5 j)	IBM_TDB	
-	2349	(T-gate\$1 or T-electrode\$1 or T-conductor\$1 or (T-shaped adj (gate\$1 or	USPAT;	2003/01/15 15:06
		electrode\$1 or conductor\$1)) or ("T" near3 (gate\$1 or electrode\$1 or	US-PGPUB;	
		conduct\$8))) and (spacer\$1 or sidewall\$1 or side-wall\$1 or (side adj	ЕРО; ЛРО;	
		wall\$1))	DERWENT; IBM_TDB	
_	876	((T-gate\$1 or T-electrode\$1 or T-conductor\$1 or (T-shaped adj (gate\$1	USPAT;	2003/01/15 15:07
	0,0	or electrode\$1 or conductor\$1)) or ("T" near3 (gate\$1 or electrode\$1 or	US-PGPUB;	
		conduct\$8))) and (spacer\$1 or sidewall\$1 or side-wall\$1 or (side adj	ЕРО; ЈРО;	
		wall\$1))) and source\$1 and drain\$1	DERWENT;	
_	852	(((T-gate\$1 or T-electrode\$1 or T-conductor\$1 or (T-shaped adj (gate\$1	IBM_TDB USPAT;	2003/01/15 15:08
-	832	or electrode\$1 or conductor\$1)) or ("T" near3 (gate\$1 or electrode\$1 or	US-PGPUB;	80.01 €111016002
		conduct\$8))) and (spacer\$1 or sidewall\$1 or side-wall\$1 or (side adj	ЕРО; ЛРО;	
		wall\$1))) and source\$1 and drain\$1) and (gate\$1 or electrode\$1)	DERWENT,	
	_		IBM_TDB	

-	70	(438/182).CCLS.	USPAT;	2003/01/15 17:09	
1			US-PGPUB	ŀ	